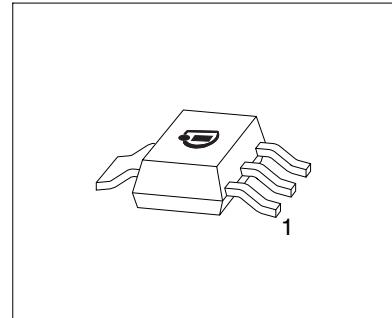


- High-side switch
- Short-circuit protection
- Input protection
- Overtemperature protection with hysteresis
- Overload protection
- Overvoltage protection
- Switching inductive load
- Clamp of negative output voltage with inductive loads
- Undervoltage shutdown
- Maximum current internally limited
- **Electrostatic discharge (ESD) protection**
- Reverse battery protection¹⁾
 - AEC qualified
 - Green product (RoHS compliant)



PG-SOT-223

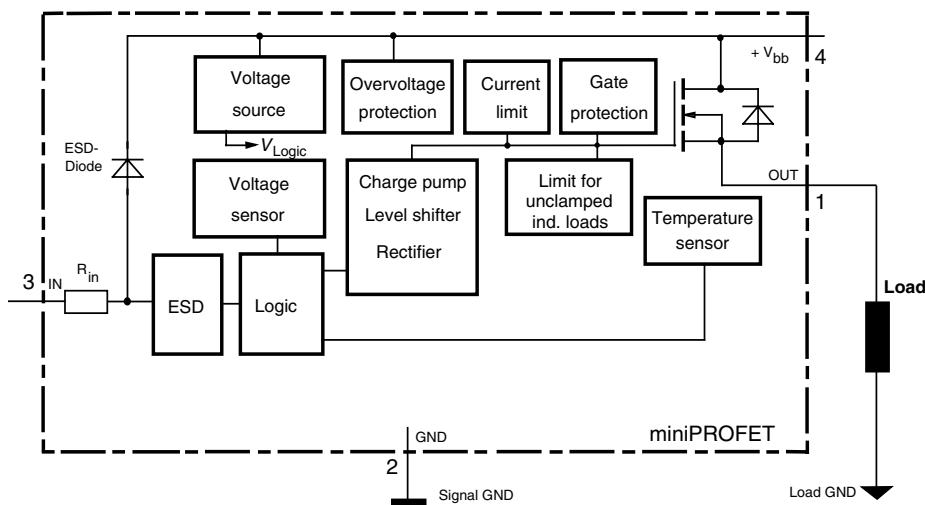
Application

- μ C compatible power switch for 12 V DC grounded loads
- All types of resistive, inductive and capacitive loads
- Replaces electromechanical relays and discrete circuits

General Description

N channel vertical power FET with charge pump, ground referenced CMOS compatible input, monolithically integrated in Smart SIPMOS® technology. Fully protected by embedded protection functions.

Blockdiagramm:



¹⁾ With resistor $R_{GND}=150 \Omega$ in GND connection, resistor in series with IN connections reverse load current limited by connected load.

Pin	Symbol	Function
1	OUT O	Output to the load
2	GND -	Logic ground
3	IN I	Input, activates the power switch in case of logical high signal
4	Vbb +	Positive power supply voltage

Maximum Ratings at $T_j = 25^\circ\text{C}$ unless otherwise specified

Parameter		Symbol	Values	Unit
Supply voltage		V_{bb}	40	V
Load current	self-limited	I_L	$I_{L(\text{SC})}$	A
Maximum input voltage ²⁾		V_{IN}	-5.0... V_{bb}	V
Maximum input current		I_{IN}	± 5	mA
Inductive load switch-off energy dissipation, single pulse	$I_L = 0.5\text{A}$, $T_A = 150^\circ\text{C}$ (not tested, specified by design)	E_{AS}	0.5	J
Load dump protection ³⁾	$V_{\text{Load Dump}} = U_A + V_s$ $R_L = 24\Omega$ $R_I = 2\Omega$, $t_d = 400\text{ms}$, IN= low or high, $U_A = 13.5\text{V}$ $R_L = 80\Omega$ (not tested, specified by design)	$V_{\text{Load dump}}^4)$	60 80	V
Electrostatic discharge capability (ESD) ⁵⁾	PIN 3 PIN 1,2,4	V_{ESD}	± 1 ± 2	kV
Operating temperature range		T_j	-40 ...+150	$^\circ\text{C}$
Storage temperature range		T_{stg}	-55 ...+150	
Max. power dissipation (DC) ⁶⁾	$T_A = 25^\circ\text{C}$	P_{tot}	1.8	W
Thermal resistance	chip - soldering point: chip - ambient: ⁶⁾	R_{thJS} R_{thJA}	7 70	K/W

²⁾ At $V_{IN} > V_{bb}$, the input current is not allowed to exceed $\pm 5\text{ mA}$.

³⁾ Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND pin, e.g. with a $150\ \Omega$ resistor in the GND connection
A resistor for the protection of the input is integrated.

⁴⁾ $V_{\text{Load dump}}$ is setup without the DUT connected to the generator per ISO 7637-1 and DIN 40839

⁵⁾ HBM according to MIL-STD 883D, Methode 3015.7

⁶⁾ BSP 452 on epoxy pcb 40 mm x 40 mm x 1.5 mm with 6 cm^2 copper area for V_{bb} connection

Electrical Characteristics

Parameter and Conditions	Symbol	Values			Unit
		min	typ	max	
at $T_j = 25^\circ\text{C}$, $V_{bb} = 13.5\text{V}$ unless otherwise specified					

Load Switching Capabilities and Characteristics

On-state resistance (pin 4 to 1) $I_L = 0.5 \text{ A}$, $V_{in} = \text{high}$ $T_j = 25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	R_{ON}	--	0.16	0.2	Ω
Nominal load current (pin 4 to 1) ⁷⁾ ISO Standard: $V_{ON} = V_{bb} - V_{OUT} = 0.5 \text{ V}$ $T_S = 85^\circ\text{C}$	$I_{L(\text{ISO})}$	0.7	--	--	A
Turn-on time to 90% V_{OUT}	t_{on}	--	60	100	μs
Turn-off time to 10% V_{OUT}	t_{off}	--	60	150	
$R_L = 24 \Omega$					
Slew rate on 10 to 30% V_{OUT} , $R_L = 24 \Omega$	dV/dt_{on}	--	2	4	$\text{V}/\mu\text{s}$
Slew rate off 70 to 40% V_{OUT} , $R_L = 24 \Omega$	$-dV/dt_{off}$	--	2	4	$\text{V}/\mu\text{s}$

Input

Allowable input voltage range, (pin 3 to 2)	V_{IN}	-3.0	--	V_{bb}	V
Input turn-on threshold voltage $T_j = -40...+150^\circ\text{C}$	$V_{IN(T+)}$	--	--	3.5	V
Input turn-off threshold voltage $T_j = -40...+150^\circ\text{C}$	$V_{IN(T-)}$	1.5	--	--	V
Input threshold hysteresis	$\Delta V_{IN(T)}$	--	0.5	--	V
Off state input current (pin 3) $V_{IN(off)} = 1.2 \text{ V}$ $T_j = -40...+150^\circ\text{C}$	$I_{IN(off)}$	10	--	60	μA
On state input current (pin 3) $V_{IN(on)} = 3.0 \text{ V to } V_{bb}$ $T_j = -40...+150^\circ\text{C}$	$I_{IN(on)}$	10	--	100	μA
Input resistance	R_{IN}	1.5	2.8	3.5	$\text{k}\Omega$

⁷⁾ $I_{L(\text{ISO})}$ is limited by current limitation, see $I_{L(\text{SC})}$, next page

Parameter and Conditions at $T_j = 25^\circ\text{C}$, $V_{bb} = 13.5\text{V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	

Operating Parameters

Operating voltage ⁸⁾	$T_j = -40 \dots +150^\circ\text{C}$	$V_{bb(on)}$	5.0	--	34	V
Undervoltage shutdown	$T_j = -40 \dots +150^\circ\text{C}$	$V_{bb(under)}$	3.5	--	5	V
Undervoltage restart	$T_j = -40 \dots +25^\circ\text{C}$ $T_j = +150^\circ\text{C}$	$V_{bb(u\ rst)}$	--	--	6.5 7.0	V
Undervoltage restart of charge pump see diagram page 7		$V_{bb(ucp)}$	--	5.6	7	V
Undervoltage hysteresis $\Delta V_{bb(under)} = V_{bb(u\ rst)} - V_{bb(under)}$		$\Delta V_{bb(under)}$	--	0.3	--	V
Oversupply shutdown	$T_j = -40 \dots +150^\circ\text{C}$	$V_{bb(over)}$	34	--	42	V
Oversupply restart	$T_j = -40 \dots +150^\circ\text{C}$	$V_{bb(o\ rst)}$	33	--	--	V
Oversupply hysteresis	$T_j = -40 \dots +150^\circ\text{C}$	$\Delta V_{bb(over)}$	--	0.7	--	V
Standby current (pin 4), $V_{in} = \text{low}$	$T_j = -40 \dots +150^\circ\text{C}$	$I_{bb(off)}$	--	10	25	μA
Operating current (pin 2), $V_{in} = 5\text{ V}$		I_{GND}	--	1	1.6	mA
leakage current (pin 1) $V_{in} = \text{low}$	$T_j = -40 \dots +25^\circ\text{C}$ $T_j = 150^\circ\text{C}$	$I_{L(off)}$	--	2	5 7	μA

Protection Functions

Current limit (pin 4 to 1)	$T_j = 25^\circ\text{C}$	$I_{L(SC)}$	0.7	1.5	2	A
$V_{bb} = 20\text{V}$	$T_j = -40 \dots +150^\circ\text{C}$		0.7	--	2.4	
Oversupply protection $I_{bb}=4\text{mA}$	$T_j = -40 \dots +150^\circ\text{C}$	$V_{bb(AZ)}$	41	--	--	V
Output clamp (ind. load switch off) at $V_{OUT}=V_{bb}-V_{ON(CL)}$, $I_{bb} = 4\text{mA}$		$V_{ON(CL)}$	41	47	--	V
Thermal overload trip temperature		T_{jt}	150	--	--	$^\circ\text{C}$
Thermal hysteresis		ΔT_{jt}	--	10	--	K
Inductive load switch-off energy dissipation ⁹⁾ $T_j \text{ Start} = 150^\circ\text{C}$, single pulse, $I_L = 0.5\text{ A}$, $V_{bb} = 12\text{ V}$ (not tested, specified by design)		E_{AS}	--	--	0.5	J
Reverse battery (pin 4 to 2) ¹⁰⁾ (not tested, specified by design)	- V_{bb}		--	--	30	V

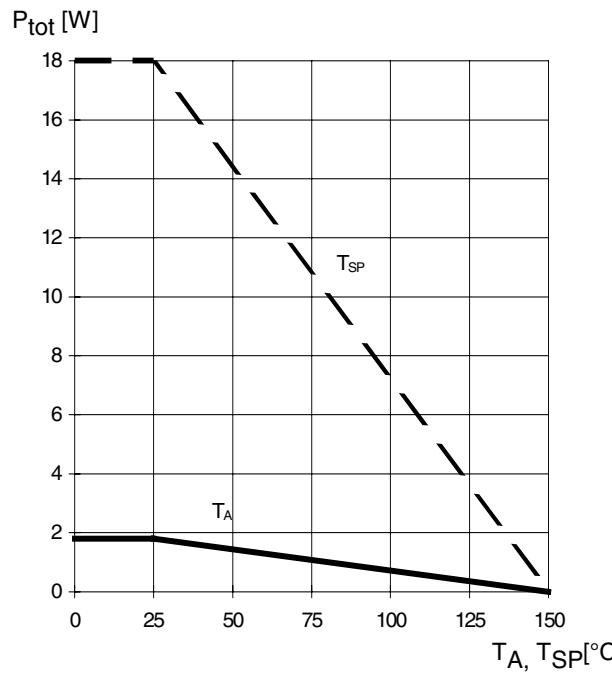
⁸⁾ At supply voltage increase up to $V_{bb} = 5.6\text{ V}$ typ without charge pump, $V_{OUT} \approx V_{bb} - 2\text{ V}$

⁹⁾ While demagnetizing load inductance, dissipated energy in PROFET is $E_{AS} = \int V_{ON(CL)} * i_L(t) dt$, approx.

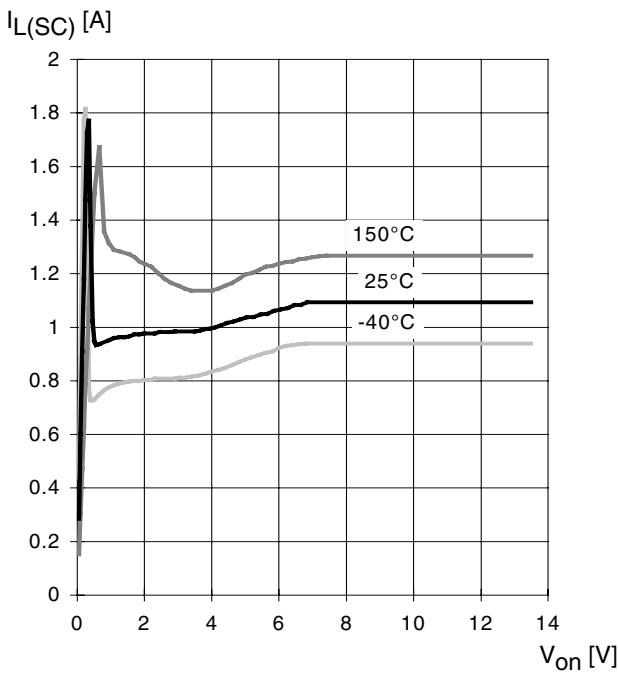
$$E_{AS} = \frac{1}{2} * L * I_L^2 * \left(\frac{V_{ON(CL)}}{V_{ON(CL)} - V_{bb}} \right)$$

¹⁰⁾ Requires $150\ \Omega$ resistor in GND connection. Reverse load current (through intrinsic drain-source diode) is normally limited by the connected load.

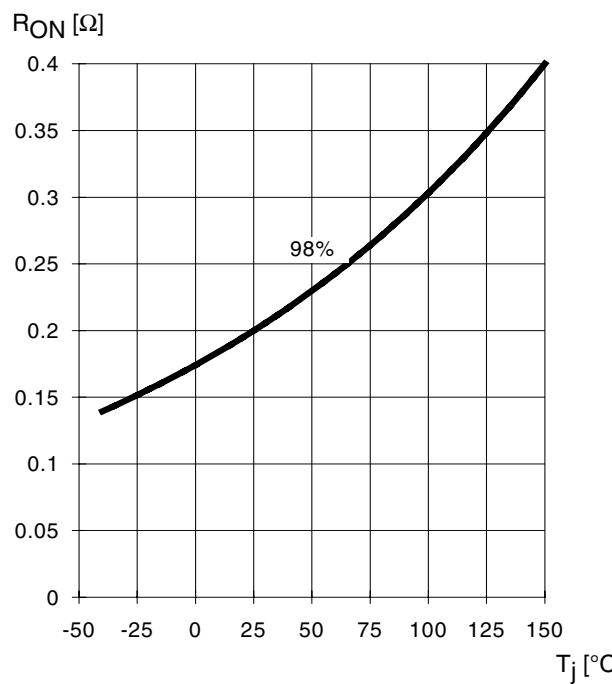
Max. allowable power dissipation
 $P_{\text{tot}} = f(T_A, T_{\text{SP}})$



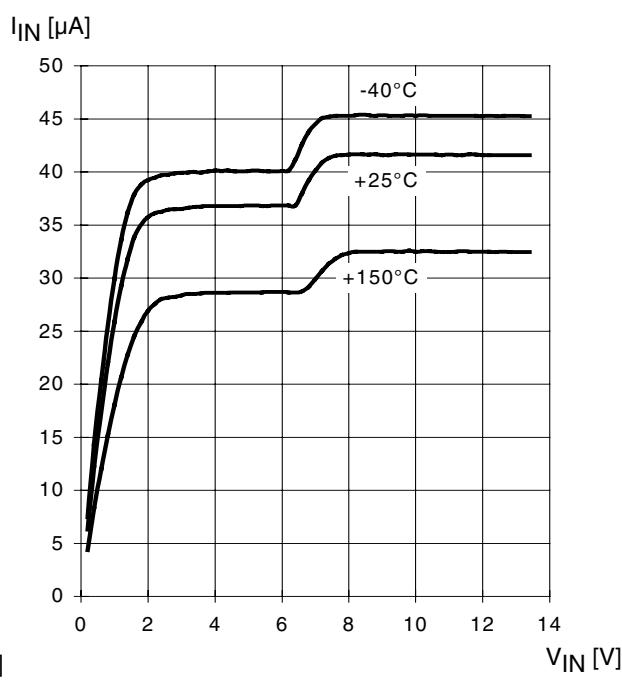
Current limit characteristic
 $I_{L(\text{SC})} = f(V_{\text{on}})$; (V_{on} see testcircuit)



On state resistance (V_{bb}-pin to OUT-pin)
 $R_{\text{ON}} = f(T_j)$; $V_{\text{bb}} = 13.5$ V; $I_L = 0.5$ A



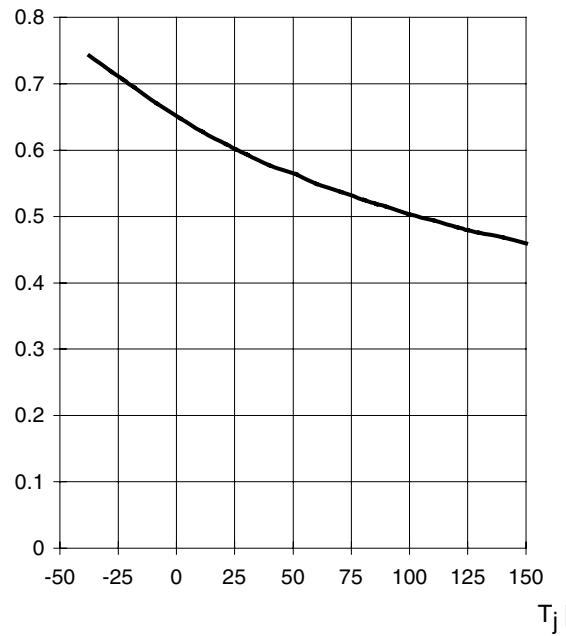
Typ. input current
 $I_{\text{IN}} = f(V_{\text{IN}})$; $V_{\text{bb}} = 13.5$ V



Typ. operating current

$I_{GND} = f(T_j)$; $V_{bb} = 13.5 \text{ V}$; $V_{IN} = \text{high}$

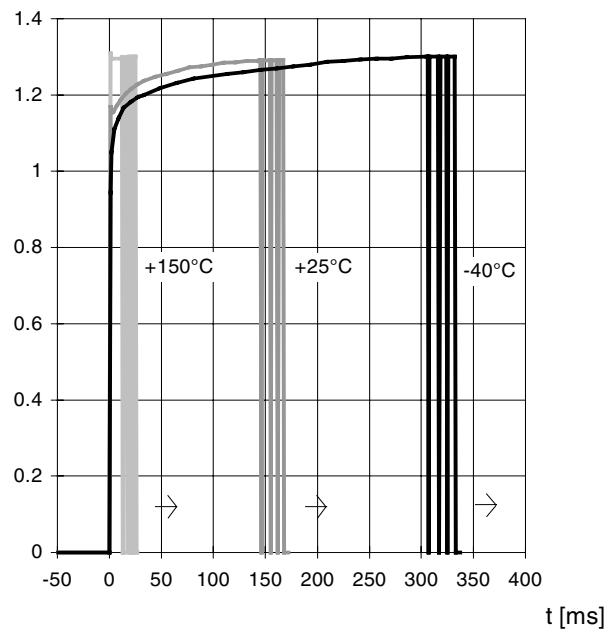
I_{GND} [mA]



Typ. overload current

$I_{L(lim)} = f(t)$; $V_{bb} = 13.5 \text{ V}$, no heatsink, Param.: T_{jstart}

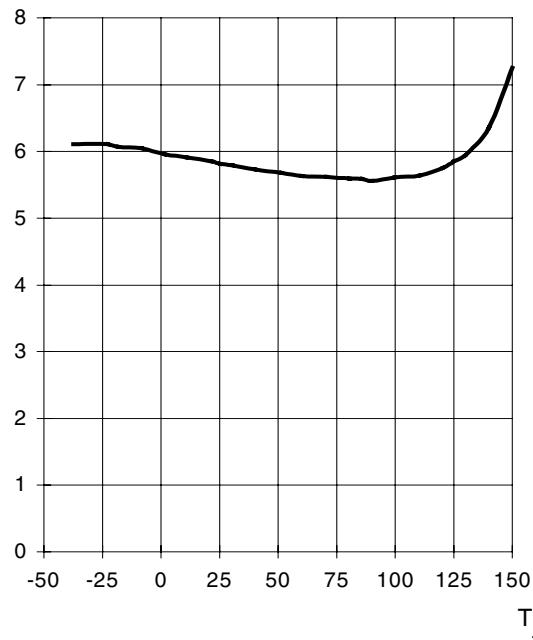
$I_{L(lim)}$ [A]



Typ. standby current

$I_{bb(off)} = f(T_j)$; $V_{bb} = 13.5 \text{ V}$; $V_{IN} = \text{low}$

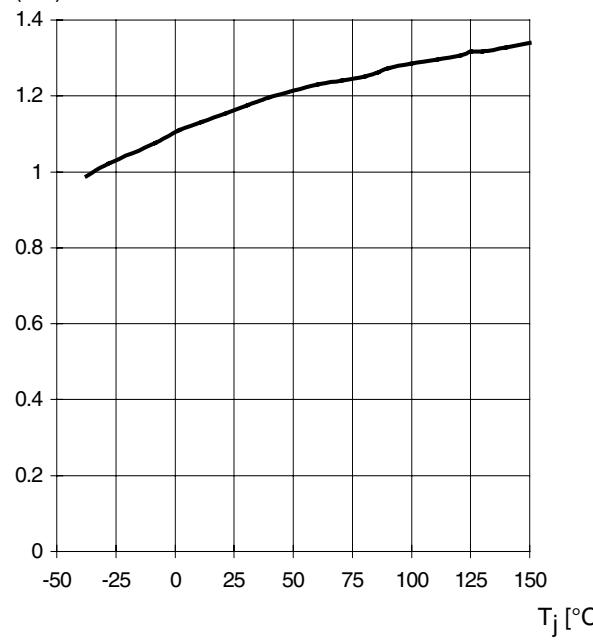
$I_{bb(off)}$ [μA]



Short circuit current

$I_{L(SC)} = f(T_j)$; $V_{bb} = 13.5 \text{ V}$

$I_{L(SC)}$ [A]



Typ. input turn on voltage threshold

$$V_{IN(T+)} = f(T_j);$$

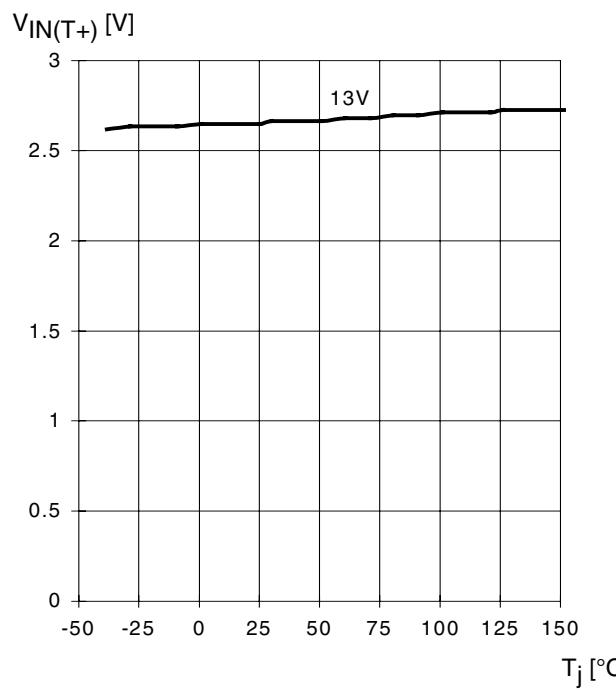
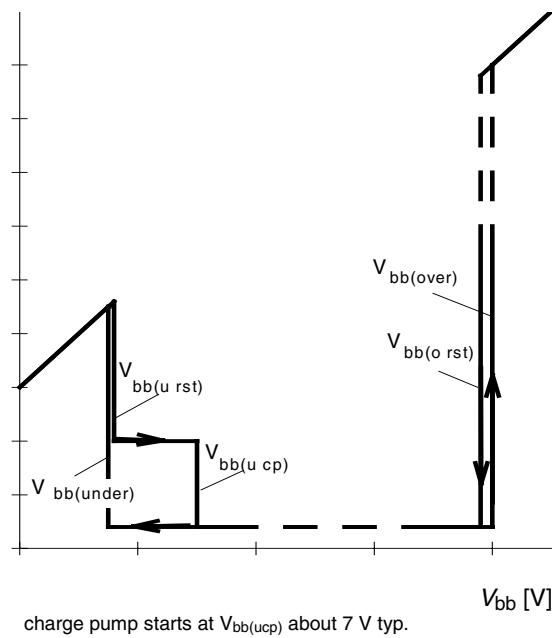


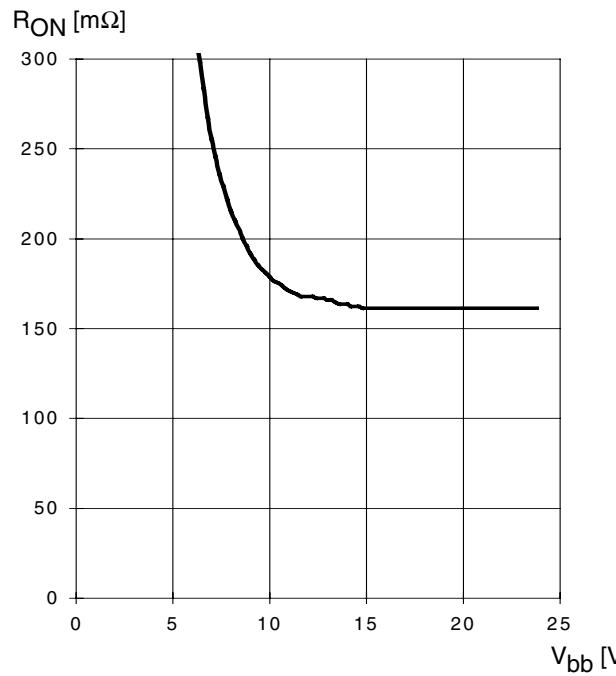
Figure 6: Undervoltage restart of charge pump

V_{ON} [V]

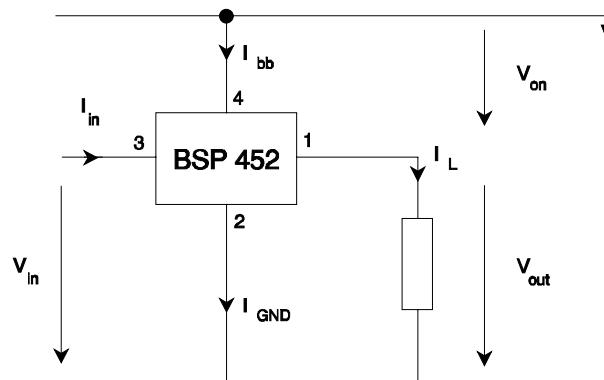


Typ. on-state resistance (Vbb-Pin to Out-Pin)

$$R_{ON} = f(V_{bb}, I_L); I_L = 0.5A, T_j = 25^\circ C$$



Test circuit



Package Outlines

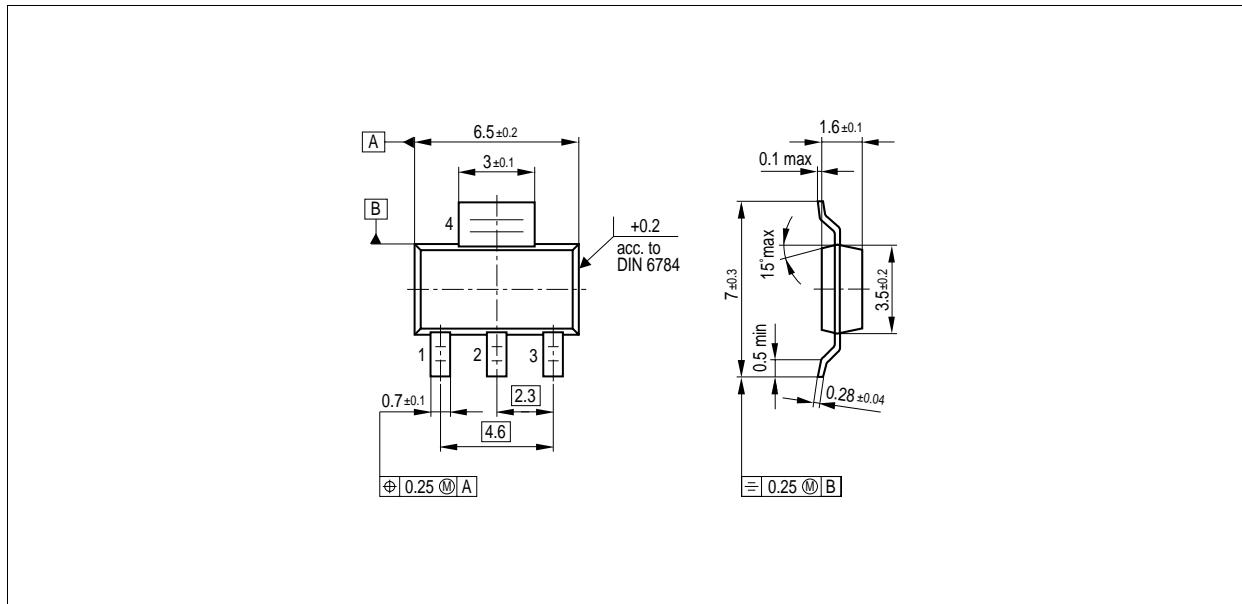


Figure 1 PG-SOT-223 (Plastic Dual Small Outline Package) (RoHS-compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

Please specify the package needed (e.g. green package) when placing an order

You can find all of our packages, sorts of packing and others in our Infineon Internet Page "Products": <http://www.infineon.com/products>.

Dimensions in mm

Revision History

Version	Date	Changes
1.0	2007-05-25	<p>Creation of the green datasheet.</p> <p>First page :</p> <p>Adding the green logo and the AEC qualified</p> <p>Adding the bullet AEC qualified and the RoHS compliant features</p> <p>Package page</p> <p>Modification of the package to be green.</p>

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